



# R-C Thermal Model Parameters

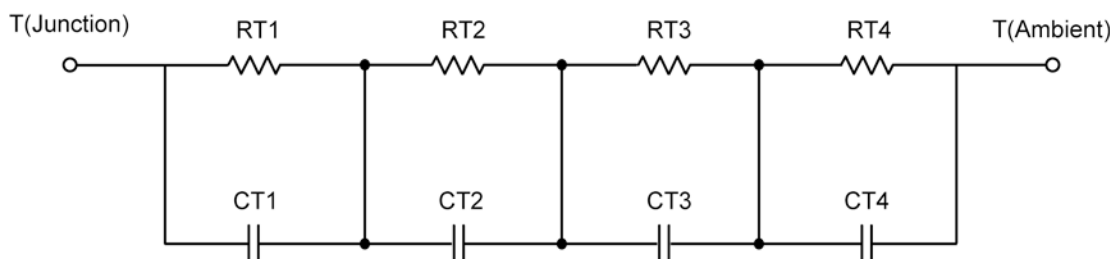
## DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

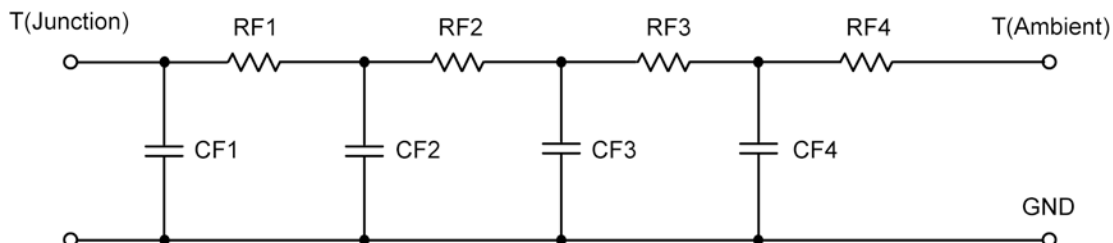
*Note:*  
For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).

## R-C THERMAL MODEL FOR TANK CONFIGURATION



| R-C VALUES FOR TANK CONFIGURATION |            |      |            |
|-----------------------------------|------------|------|------------|
| Thermal Resistance (°C/W)         |            |      |            |
| Junction to                       | Ambient    | Case | Foot       |
| RT1                               | 30.3122    | N/A  | 5.9888     |
| RT2                               | 30.5137    | N/A  | 22.2008    |
| RT3                               | 5.4749     | N/A  | 4.8192     |
| RT4                               | 58.6992    | N/A  | 11.9912    |
| Thermal Capacitance (Joules/°C)   |            |      |            |
| Junction to                       | Ambient    | Case | Foot       |
| CT1                               | 1.6745 m   | N/A  | 275.9981 m |
| CT2                               | 22.5192 m  | N/A  | 3.0278 m   |
| CT3                               | 128.6939 u | N/A  | 157.2160 u |
| CT4                               | 1.3009     | N/A  | 1.2711 m   |

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

**R-C THERMAL MODEL FOR FILTER CONFIGURATION****R-C VALUES FOR FILTER CONFIGURATION**

| Thermal Resistance ( $^{\circ}\text{C}/\text{W}$ ) |            |      |            |
|--|------------|------|------------|
| Junction to  | Ambient    | Case | Foot       |
| RF1  | 9.4922     | N/A  | 9.2904     |
| RF2  | 31.6850    | N/A  | 23.1352    |
| RF3  | 26.5418    | N/A  | 7.6691     |
| RF4  | 57.2810    | N/A  | 4.9053     |
| Thermal Capacitance (Joules/ $^{\circ}\text{C}$ )  |            |      |            |
| Junction to  | Ambient    | Case | Foot       |
| CF1  | 206.0568 u | N/A  | 179.4734 u |
| CF2  | 1.7424 m   | N/A  | 1.1361 m   |
| CF3  | 23.8550 m  | N/A  | 8.5508 m   |
| CF4  | 1.3148     | N/A  | 398.0373 m |

Note: NA indicates not applicable

## Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya. IEEE / SEMITHERM 2002

